

CRYSTAL OSCILLATOR (SPXO)

OUTPUT : CMOS, TTL

SG-615 series SG-531/SG-51 series

•Frequency range : 1.025 MHz to 135 MHz •Supply voltage : 3.3 V Typ. / 5.0 V Typ.

 $\begin{array}{ll} \bullet \text{Function} & : \quad \text{Output enable(OE) or Standby(} \, \overline{\text{ST}} \,) \\ \bullet \text{Pin compatible with full-size metal can. (SG-51 series)} \\ \bullet \text{Pin compatible with half-size metal can. (SG-531 series)} \\ \end{array}$



Product Number (please contact us)
SG-615 : Q33615xx2xxxx00
SG -531 : Q32531xx2xxxx00
SG -51 : Q32510xx2xxxx00







Actual size

SG-615





SG-51 E SG51P 9353B 16.0000MHz C

Specifications (characteristics)

		Specifica			
Item	Symbol	SG-615P SG-615PTJ SG-531P SG-531PTJ SG-51P SG-51PTJ		Conditions / Remarks	
Output frequency range	fo	1.025 MHz to 26 MHz	26.001 MHz to 66.667 MHz	Please contact us about available frequencies.	
Supply voltage	Vcc	5.0 V ±0	0.5 V		
Storage temperature	T_stg	-55 °C to +	+125 °C	Storage as single product.	
Operating temperature	T_use	-20 °C to	+70 °C		
Frequency tolerance	f tol	B^{-1} : $\pm 50 \times 10^{-6}$, C: $\pm 100 \times 10^{-6}$		-20 °C to +70 °C	
Current consumption	Icc	23 mA Max.	35 mA Max.	No load condition	
Disable current	I_dis	12 mA Max.	28 mA Max.	OE=GND	
Symmetry	SYM	40 % to 60 %	_	CMOS load:50 % Vcc level	
Symmetry		40 % to 60 %	45 % to 55 %	TTL load: 1.4 V level	
Output voltage	Vон	Vcc-0.4 V Min.	2.4 V Min.	Іон=-400 μА	
1 0	Vol	0.4 V Max.		IoL=16 mA(P)/ 8 mA(PTJ)	
Output load condition (TTL)	L_TTL	10 TTL Max.	5 TTL Max.	$L_CMOS \le 15 pF$	
Output load condition (CMOS)	L_CMOS	50 pF Max.			
Input voltage	VIH	2.0 V Min.	3.5 V Min.	I _{IH} = 1 μA Max. (OE=Vcc)	
	VIL	0.8 V Max.	1.5 V Max.	IιL= -100 μA Min. (OE=GND), PTJ:IιL= -500 μA Min.(OE=GND)	
Rise time / Fall time	tr / tf	8 ns Max.	_	CMOS load:20 % Vcc to 80 % Vcc level	
		8 ns Max.	5 ns Max.	TTL load:0.4 V to 2.4 V level	
Start-up time	t_str	4 ms Max.	10 ms Max.	Time at minimum supply voltage to be 0 s	
Frequency aging	f_aging	$\pm 5 \times 10^{-6}$ / y	$\pm 5 \times 10^{-6}$ / year Max. +25		

^{*1 &}quot;B" tolerance will be available up to 55 MHz.

Specifications (characteristics)

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	Symbol	Specifications			
Item		SG-615PCG SG-531PCG	SG-615SCG SG-531SCG	SG-615PCN	Conditions / Remarks
Output frequency range	fo	1.500 MHz to 26.000 MHz		26.001 MHz to 66.667 MHz	Please contact us about available frequencies.
Supply voltage	Vcc	2.7 V to 3.6 V 3.0 V		3.0 V to 3.6 V	
Storage temperature	T_stg	-55 °C to +125 °C		Storage as single product.	
Operating temperature	T_use	-40 °C to +85 °C			
Fraguency toloropeo	f_tol	B: ±50 × 10 ⁻⁶ C: ±100 × 10 ⁻⁶			-20 °C to +70 °C
Frequency tolerance		M: ±100 × 10 ⁻⁶			-40 °C to +85 °C
Current consumption	Icc	12 mA Max. 20 mA Max		20 mA Max.	No load condition
Disable current	I_dis	10 mA Max.		10 mA Max.	OE=GND (PCG,PCN)
Stand-by current	l_std	— 50 μA Max.			ST =GND (SCG)
Symmetry	SYM	45 % to 55 %		50 % Vcc level, L_CMOS=Max.	
Output voltage	Vон	Vcc-0.4 V Min.		Vcc-0.4 V Min.	Iон=-8 mA
Output voltage	Vol	0.4 V Max.		0.4 V Max.	IoL= 8 mA
Output load condition	L_CMOS	25 pF Max.		15 pF Max.	
Input voltage	ViH	70 % Vcc Min.		70 % Vcc Min.	OE Terminal or ST Terminal
	VIL	20 % Vcc Max.		30 % Vcc Max.	
Rise time / Fall time	tr / tf	4 ns Max.		20 % Vcc to 80 % Vcc level, L_CMOS ≤ Max.	
Start-up time	t_str	12 ms Max. 10 ms		10 ms Max.	t=0 at 90% Vcc
Frequency aging	f_aging	$\pm 5 \times 10^{-6}$ / year Max.			+25 °C, Vcc=3.3 V, First year



Specifications (characteristics)

		Specifications			
Item	Symbol	SG-615PTW / STW	SG-615PHW / SHW	SG-615PCW / SCW	Conditions / Remarks
		SG-531PTW / STW	SG-531PHW/SHW	SG-531PCW / SCW	
Output frequency range	fo	55 001 MHz to	135 000 MHz	26.001 MHz to	Please contact us about available frequencies.
		55.001 MHz to 135.000 MHz		135.000 MHz	riease contact us about available frequencies.
Supply voltage	Vcc	5.0 V	±0.5 V	3.3 V ±0.3 V	
Storage temperature	T_stg	-55 °C to +125 °C		Storage as single product.	
Operating temperature	T_use	-20 °C to +70 °C			
Eroguanov talaranaa	f tol	B: ±50 × 10 ⁻⁶ , C ⁻² : ±100 × 10 ⁻⁶			-20 °C to +70 °C
Frequency tolerance	f_tol	-	_	M: ±100 × 10 ⁻⁶	-40 °C to +85 °C
Current consumption	Icc	45 mA Max. 28 mA Max.		28 mA Max.	No load condition(Max. frequency range)
Disable current	I_dis	30 mA Max. 16 mA Max.		OE=GND (PTW,PHW,PCW)	
Stand-by current	I_std	50 μA Max.		ST =GND (STW,SHW,SCW)	
Symmetry	SYM	— 40 % to 60 %		50 % Vcc level, L_CMOS=Max.	
Symmetry	3110	40 % to 60 %		1.4 V level ,L_CMOS=Max.	
Output voltage	Vон	Vcc-0.4 V Min.		IOH=-16 mA(PTW,STW,PHW,SHW),-8 mA(PCW,SCW)	
Output voltage	Vol	0.4 V Max.		IoL= 16 mA(PTW,STW,PHW,SHW), 8 mA(PCW,SCW)	
Output load condition (TTL)	L_TTL	5 TTL Max.	_	_	fo ≤ 90 MHz , Max.supply voltage
Output load condition (CMOS)	L_CMOS	15 pF Max.		Max.frequency , Max.supply voltage	
Input voltage	ViH	2.0 V Min. 70 % Vcc Min.		70 % Vcc Min.	OE Terminal or ST Terminal
	VIL	0.8 V Max. 20 % Vcc Max.		OE leminarors reminar	
Rise time / Fall time	tr / tf	— 4 ns Max.		20 % Vcc to 80 % Vcc level, L_CMOS ≤ Max.	
Nise unie / i all unie		4 ns Max.		_	0.4 V to 2.4 V level
Start-up time	t_str	10 ms Max		Time at minimum supply voltage to be 0 s	
Frequency aging	f aging	$\pm 5 \times 10^{-6}$ / year Max.		+25 °C, Vcc=5.0 V / 3.3 V, First year	

^{*2 &}quot;C" tolerance : fo ≥66.667 MHz(PTW,STW,PHW,SHW)

Product Name (Standard form) SG-615 P C G 20.000000MHz C 1 4

①Model ②Function (P: Output enable, S:Standby)

⑤Frequency tolerance

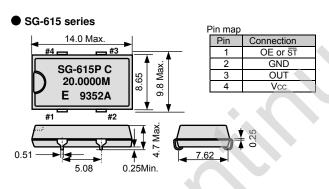
③Supply voltage		
С	3.3 V Typ.	
T,H	5.0 V Typ.	
Blank	5.0 V Typ.	

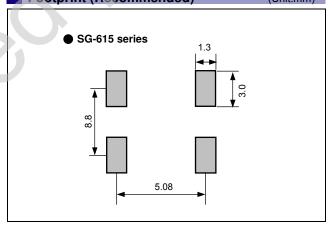
	⑤Frequency tolerance				
۷	В	±50 × 10 ⁻⁶ / -20 to +70°C			
L.	С	±100 × 10 ⁻⁶ / -20 to +70°C			
	M	±100 × 10 ⁻⁶ / -40 to +85°C			

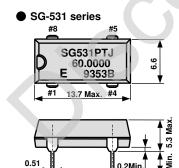
External dimensions

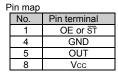
(Unit:mm)

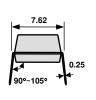
Footprint (Recommended) (Unit:mm)

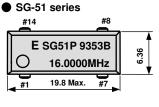


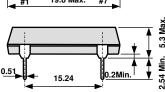


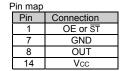


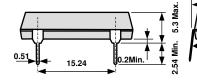














Note:

OE pin (P,PTJ,PTW,PHW,PCW,PCN,PCG)

OE pin = "H" or "open" : Specified frequency output.

OE pin = "L" : Output is high impedance.

ST pin (STW, SHW, SCW,SCG)

ST pin = "H" or "open" : Specified frequency output.
ST pin = "L" : Output is low level

(weak pull - down),oscillation stops.

To maintain stable operation, provide a 0.01uF to 0.1uF by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between Vcc - GND).

PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Seiko Epson, all environmental initiatives operate under the Plan-Do-Check-Action (PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation.

WORKING FOR HIGH QUALITY

In order provide high quality and reliable products and services than meet customer needs,

Seiko Epson made early efforts towards obtaining ISO9000 series certification and has acquired ISO9001 for all business establishments in Japan and abroad. We have also acquired ISO/TS 16949 certification that is requested strongly by major automotive manufacturers as standard.

ISO/TS16949 is the international standard that added the sector-specific supplemental requirements for automotive industry based on ISO9001.

Explanation of the mark that are using it for the catalog



►Pb free.



- ► Complies with EU RoHS directive.
 - *About the products without the Pb-free mark.

 Contains Pb in products exempted by EU RoHS directive.

 (Contains Pb in sealing glass, high melting temperature type solder or other.)



▶ Designed for automotive applications such as Car Multimedia, Body Electronics, Remote Keyless Entry etc.



▶ Designed for automotive applications related to driving safety (Engine Control Unit, Air Bag, ESC etc).

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